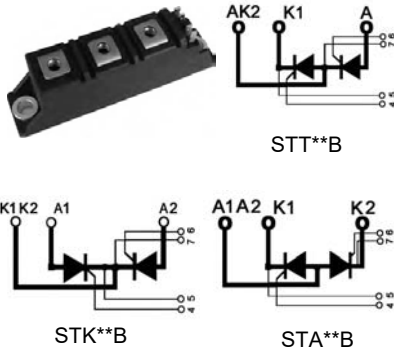


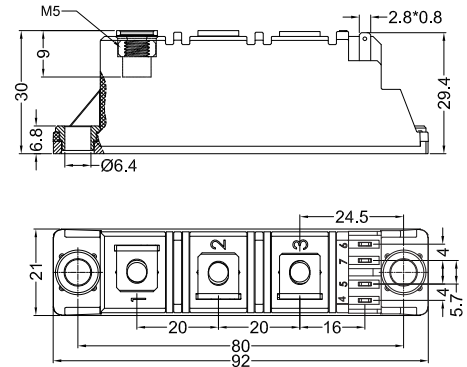
# STT/STA/STK90GKXXB

## Thyristor-Thyristor Modules



Type	$V_{RSM}$	$V_{RRM}$
	$V_{DSM}$	$V_{DRM}$
	V	V
STT(STA/STK)90GK08B	900	800
STT(STA/STK)90GK12B	1300	1200
STT(STA/STK)90GK14B	1500	1400
STT(STA/STK)90GK16B	1700	1600
STT(STA/STK)90GK18B	1900	1800
STT(STA/STK)90GK20B	2100	2000

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
$I_{TRMS}, I_{FRMS}$ $I_{TAVM}, I_{FAVM}$	$T_V = T_{VJM}$ $T_C = 85^\circ C$ ; 180° sine	140 90	A
$I_{TSM}, I_{FSM}$	$T_V = 45^\circ C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	1700 1800	A
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	1540 1640	
$\int i^2 dt$	$T_V = 45^\circ C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	14450 13500	$A^2s$
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	11850 11300	
$(di/dt)_{cr}$	$T_V = T_{VJM}$ $f = 50Hz, t_p = 200us$ $V_D = 2/3 V_{DRM}$ $I_G = 0.45A$ $di/dt = 0.45A/us$ repetitive, $I_T = 250A$	150	A/us
	non repetitive, $I_T = I_{TAVM}$	500	
$(dv/dt)_{cr}$	$T_V = T_{VJM}$ ; $R_{GK} = \infty$ ; method 1 (linear voltage rise) $V_{DR} = 2/3 V_{DRM}$	1000	V/us
$P_{GM}$	$T_V = T_{VJM}$ $I_T = I_{TAVM}$ $t_p = 30us$	10	W
	$t_p = 300us$	5	
$P_{GAV}$		0.5	W
$V_{RGM}$		10	V
$T_{VJ}$ $T_{VJM}$ $T_{stg}$		-40...+125	$^\circ C$
		125	
		-40...+125	
$V_{ISOL}$	50/60Hz, RMS $I_{ISOL} \leq 1mA$ $t = 1min$	3000	V~
	$t = 1s$	3600	
$M_d$	Mounting torque (M5)	2.5-4.0/22-35	Nm/lb.in.
	Terminal connection torque (M5)	2.5-4.0/22-35	
<b>Weight</b>	Typical	110	g

**Sirectifier**®

# STT/STA/STK90GKXXB

## Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
<b>I<sub>RRM</sub>, I<sub>DRM</sub></b>	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	5	mA
<b>V<sub>TM</sub></b>	$I_{TM}=270A; T_{VJ}=25^{\circ}C$	1.64	V
<b>V<sub>TO</sub></b>	For power-loss calculations only ( $T_{VJ}=125^{\circ}C$ )	0.85	V
<b>r<sub>T</sub></b>		3.2	mΩ
<b>V<sub>GT</sub></b>	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	2.5 2.6	V
<b>I<sub>GT</sub></b>	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	150 200	mA
<b>V<sub>GD</sub></b>	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
<b>I<sub>GD</sub></b>		10	mA
<b>I<sub>L</sub></b>	$T_{VJ}=25^{\circ}C; t_p=10\mu s; V_D=6V$ $I_G=0.45A; di_G/dt=0.45A/\mu s$	450	mA
<b>I<sub>H</sub></b>	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	200	mA
<b>t<sub>gd</sub></b>	$T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.45A; di_G/dt=0.45A/\mu s$	2	us
<b>t<sub>q</sub></b>	$T_{VJ}=T_{VJM}; I_T=150A; t_p=200\mu s; -di/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$ typ.	185	us
<b>Q<sub>s</sub></b>	$T_{VJ}=T_{VJM}; I_T, I_F=50A; -di/dt=6A/\mu s$	170	uC
<b>I<sub>RM</sub></b>		45	A
<b>R<sub>thJC</sub></b>	per thyristor/diode; DC current per module	0.3 0.15	K/W
<b>R<sub>thJK</sub></b>	per thyristor/diode; DC current per module	0.5 0.25	K/W
<b>d<sub>s</sub></b>	Creeping distance on surface	12.7	mm
<b>d<sub>A</sub></b>	Strike distance through air	9.6	mm
<b>a</b>	Maximum allowable acceleration	50	m/s <sup>2</sup>

### FEATURES

- \* International standard package
- \* Copper base plate
- \* Glass passivated chips
- \* Isolation voltage 3600 V~
- \* UL file NO.E310749
- \* RoHS compliant

### APPLICATIONS

- \* DC motor control
- \* Softstart AC motor controller
- \* Light, heat and temperature control

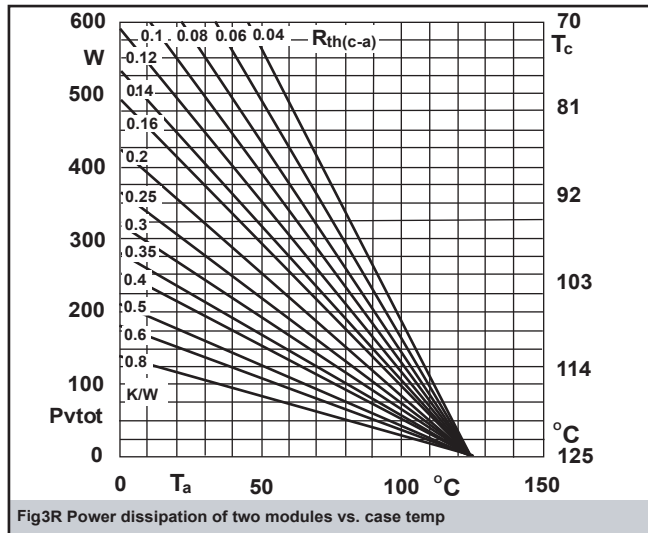
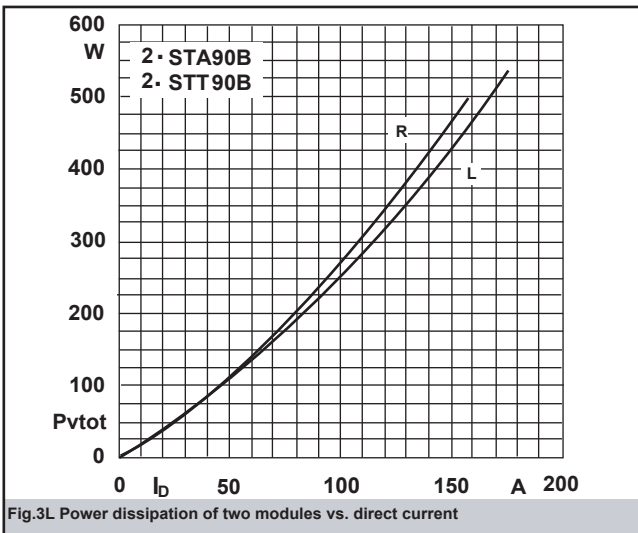
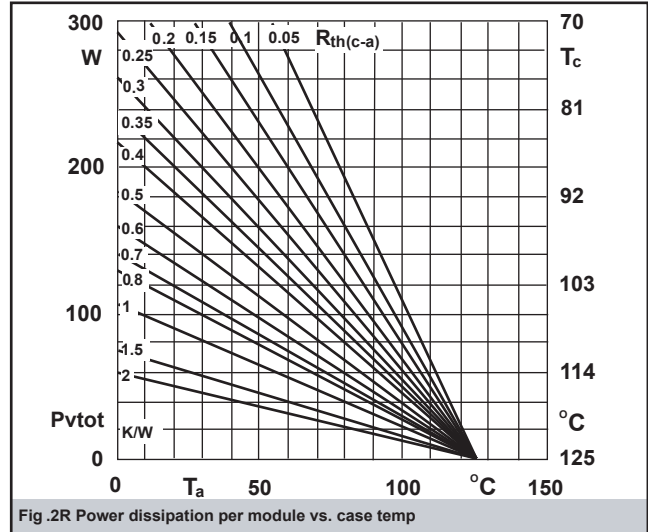
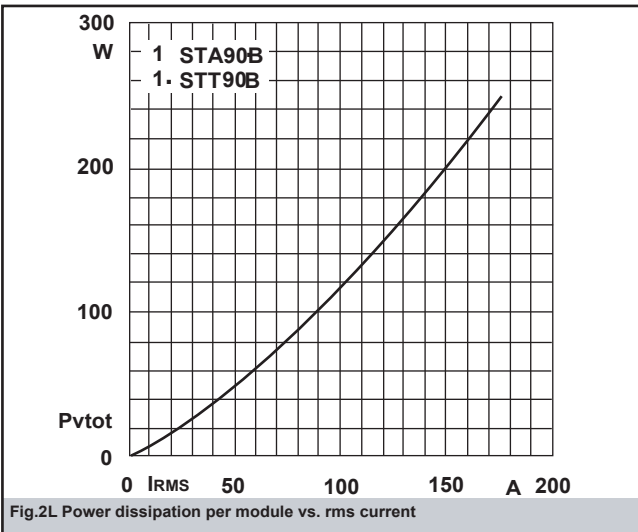
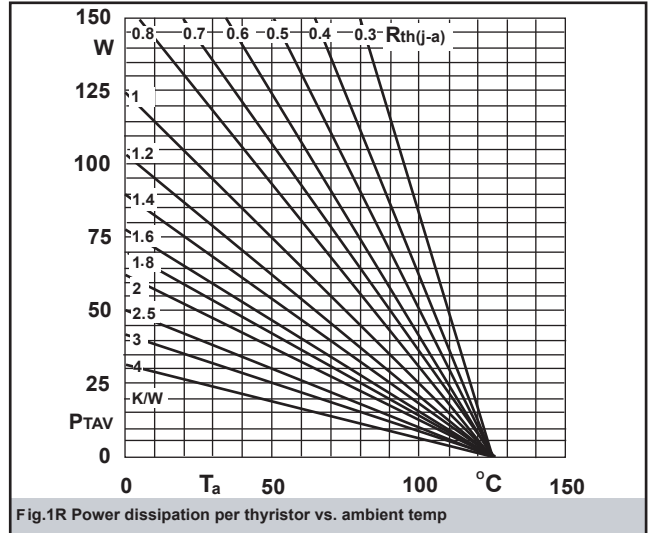
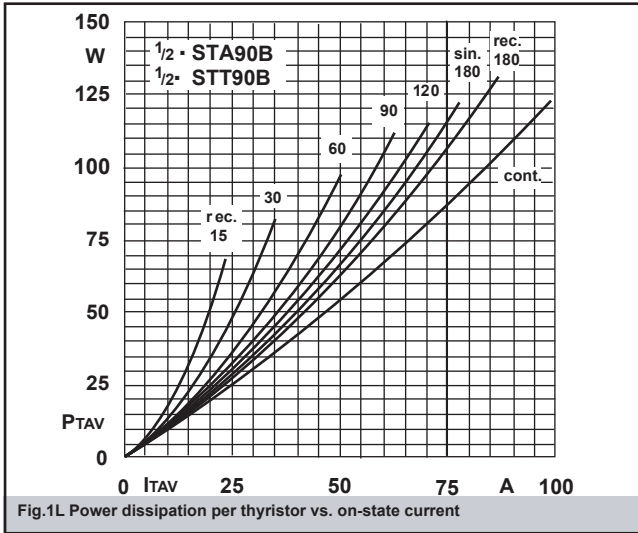
### ADVANTAGES

- \* Space and weight savings
- \* Simple mounting with two screws
- \* Improved temperature and power cycling
- \* Reduced protection circuits



# STT/STA/STK90GKXXB

## Thyristor-Thyristor Modules



# STT/STA/STK90GKXXB

## Thyristor-Thyristor Modules

